TEXAS INSTRUMENTS
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TS5N412
4-BIT 1-OF-2 FET MULTIPLEXER/DEMULTIPLEXER HIGH-BANDWIDTH BUS SWITCH

SCDS207–AUGUST 2005

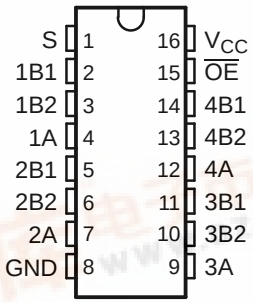
FEATURES

- Low and Flat ON-State Resistance (r_{on}) Characteristics Over Operating Range (r_{on} = 3 Ω Typ)
- 0- to 10-V Switching on Data I/O Ports
- Bidirectional Data Flow With Near-Zero Propagation Delay
- Low Input/Output Capacitance Minimizes Loading and Signal Distortion ($C_{io(OFF)}$ = 20 pF Max, B Port)
- V_{CC} Operating Range From 4.75 V to 5.25 V
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
  - 2000-V Human-Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)
- Supports Both Digital and Analog Applications

APPLICATIONS

- PCI Interface
- Differential Signal Interface
- Memory Interleaving
- Bus Isolation
- Low-Distortion Signal Gating

DBQ OR PW PACKAGE
(TOP VIEW)



DESCRIPTION/ORDERING INFORMATION

The TS5N412 is a high-bandwidth FET bus switch utilizing a charge pump to elevate the gate voltage of the pass transistor, providing a low and flat ON-state resistance (r_{on}). The low and flat ON-state resistance allows for minimal propagation delay and supports rail-to-rail switching on the data input/output (I/O) ports. The device also features low data I/O capacitance to minimize capacitive loading and signal distortion on the data bus. Specifically designed to support high-bandwidth applications, the TS5N412 provides an optimized interface solution ideally suited for broadband communications, networking, and data-intensive computing systems.

The TS5N412 is a 4-bit 1-of-2 multiplexer/demultiplexer with a single output-enable ($\overline{OE}$) input. The select (S) inputs control the data path of the multiplexer/demultiplexer. When $\overline{OE}$ is low, the multiplexer/demultiplexer is enabled and the A port is connected to the B port, allowing bidirectional data flow between ports. When $\overline{OE}$ is high, the multiplexer/demultiplexer is disabled and a high-impedance state exists between the A and B ports.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry prevents damaging current backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

ORDERING INFORMATION

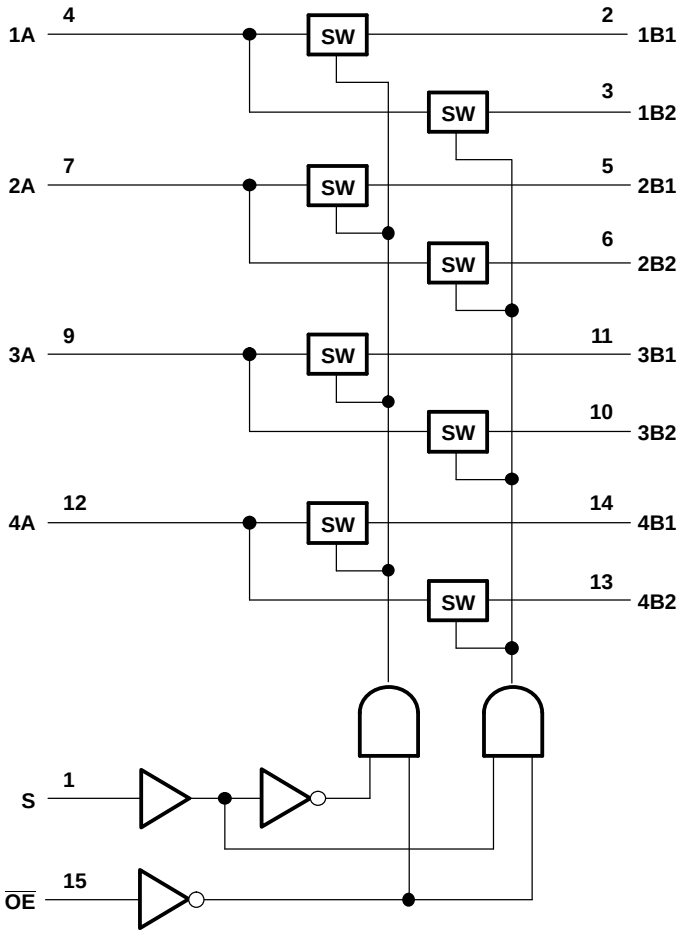
T_A	PACKAGE(1)		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	SSOP (QSOP) – DBQ	Tape and reel	TS5N412DBQR	YB412
	TSSOP – PW	Tape and reel	TS5N412PWR	

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

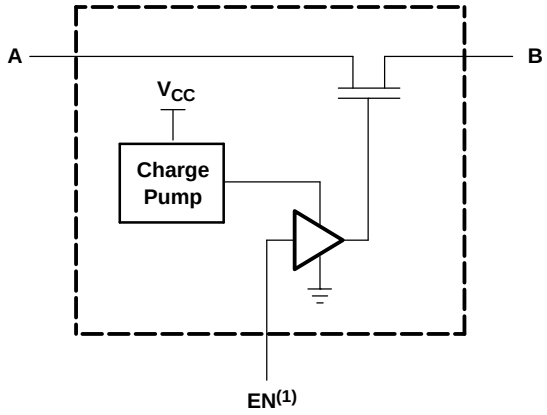
FUNCTION TABLE

INPUTS		INPUT/OUTPUT A	FUNCTION
$\overline{OE}$	S		
L	L	B1	A port = B1 port
L	H	B2	A port = B2 port
H	X	Z	Disconnect

LOGIC DIAGRAM (POSITIVE LOGIC)



SIMPLIFIED SCHEMATIC, EACH FET SWITCH (SW)



(1) EN is the internal enable signal applied to the switch.

Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		–0.5	7	V
V_{IN}	Control input voltage range(2)(3)		–0.5	7	V
$V_{I/O}$	Switch I/O voltage range(2)(3)(4)		–0.5	11	V
$I_{I/O}$	ON-state switch current(5)			±100	mA
	Continuous current through V_{CC} or GND			±100	mA
θ_{JA}	Package thermal impedance(6)	DBQ package		90	°C/W
		PW package		108	
T_{stg}	Storage temperature range		–65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltages are with respect to ground, unless otherwise specified.
(3) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
(4) V_I and V_O are used to denote specific conditions for $V_{I/O}$.
(5) I_I and I_O are used to denote specific conditions for $I_{I/O}$.
(6) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions(1)

		MIN	MAX	UNIT
V_{CC}	Supply voltage	4.75	5.25	V
V_{IH}	High-level control input voltage	2	5.25	V
V_{IL}	Low-level control input voltage	0	0.8	V
$V_{I/O}$	Data input/output voltage	0	10	V
T_A	Operating free-air temperature	–40	85	°C

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

Electrical Characteristics(1)

over recommended operating free-air temperature range, (unless otherwise noted)

PARAMETER		TEST CONDITIONS			MIN	TYP(2)	MAX	UNIT
I_{IN}	Control inputs	V_{CC} = 5.25 V,	V_{IN} = 0 to V_{CC}				10	μA
I_{OZ}(3)		V_{CC} = 5.25 V,	V_O = 0 to 10 V, V_I = 0,	Switch OFF, V_{IN} = V_{CC} or GND			10	μA
		V_{CC} = 0 V,	V_O = Open,	V_I = 0 to 10 V			10	
I_{CC}		V_{CC} = 5.25 V,	$I_{I/O}$ = 0, Switch ON or OFF,	V_{IN} = V_{CC} or GND			10	mA
C_{in}	Control inputs	V_{CC} = 5 V,	V_{IN} = 10 V or 0				10	pF
$C_{io(OFF)}$	A port	V_{CC} = 5 V,	Switch OFF, V_{IN} = V_{CC} or GND,	$V_{I/O}$ = 10 V or 0			35	pF
	B port	V_{CC} = 5 V,	Switch OFF, V_{IN} = V_{CC} or GND,	$V_{I/O}$ = 10 V or 0			20	
$C_{io(ON)}$		V_{CC} = 5 V,	Switch ON, V_{IN} = V_{CC} or GND,	$V_{I/O}$ = 10 V or 0			80	pF
r_{on}(4)		V_{CC} = 4.75 V, TYP at V_{CC} = 5 V	V_I = 0,	I_O = 50 mA		3	7.5	Ω
			V_I = 8 V,	I_O = –50 mA			7.5	
			V_I = 10 V,	I_O = –50 mA			12.5	

(1) V_{IN} and I_{IN} refer to control inputs. V_I, V_O, I_I, and I_O refer to data pins
(2) All typical values are at V_{CC} = 5 V (unless otherwise noted), T_A = 25°C.
(3) For I/O ports, the parameter I_{OZ} includes the I/O leakage current.
(4) Measured by the voltage drop between the A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} = 5 V ± 0.25 V		UNIT
			MIN	MAX	
t_{pd}(1)	A or B	B or A		3	ns
$t_{pd(s)}$	S	A		200	ns
t_{en}	S	B		200	ns
	$\overline{OE}$	A or B		200	
t_{dis}	S	B		200	ns
	OE	A or B		200	

(1) The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

Dynamic Characteristics

over recommended operating free-air temperature range, V_{CC} = 5 V ± 5% (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
Bandwidth (BW)(2)	R_L = 50 Ω, V_I = 0.632 V (P-P), See Figure 4	25			MHz
OFF isolation (O_{ISO})	R_L = 50 Ω, V_I = 0.632 V (P-P), f = 25 MHz, See Figure 5		–50		dB
Crosstalk (X_{TALK})	R_L = 50 Ω, V_I = 0.632 V (P-P), f = 25 MHz, See Figure 6 and Figure 7		–50		dB

(1) All typical values are at V_{CC} = 5 V (unless otherwise noted), T_A = 25°C.
(2) Bandwidth is the frequency at which the gain is –3 dB below the DC gain.

TYPICAL PERFORMANCE

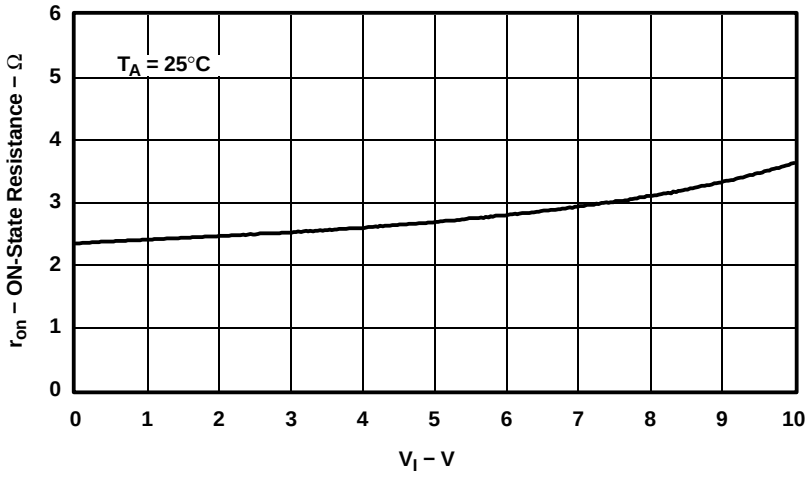


Figure 1. Typical r_{on} vs V_I, V_{CC} = 5 V and I_O = –50 mA

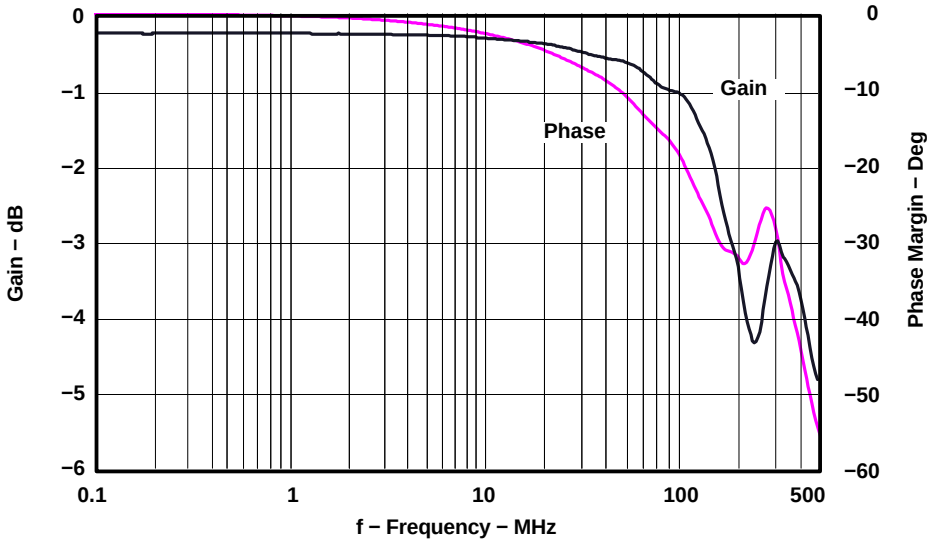


Figure 2. Frequency Response vs Bandwidth

TYPICAL PERFORMANCE

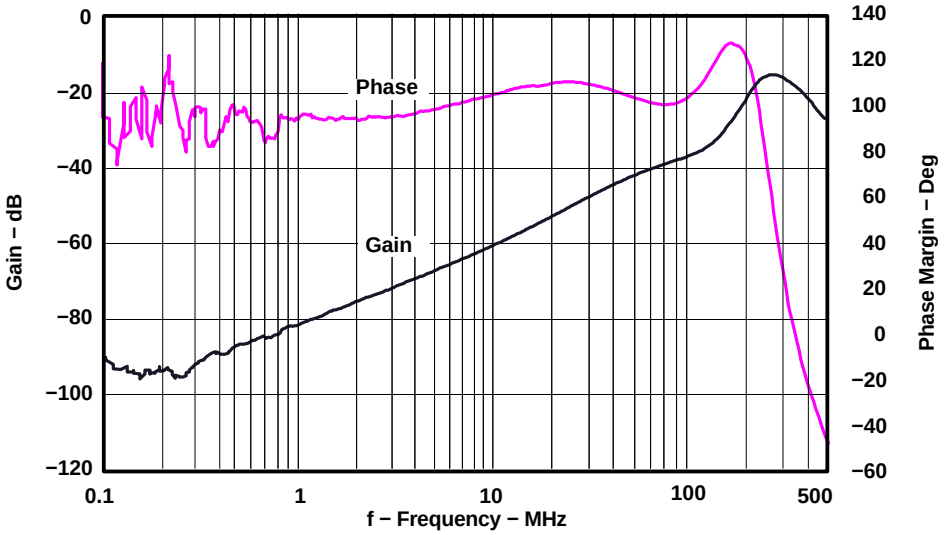


Figure 3. Frequency Response vs OFF Isolation

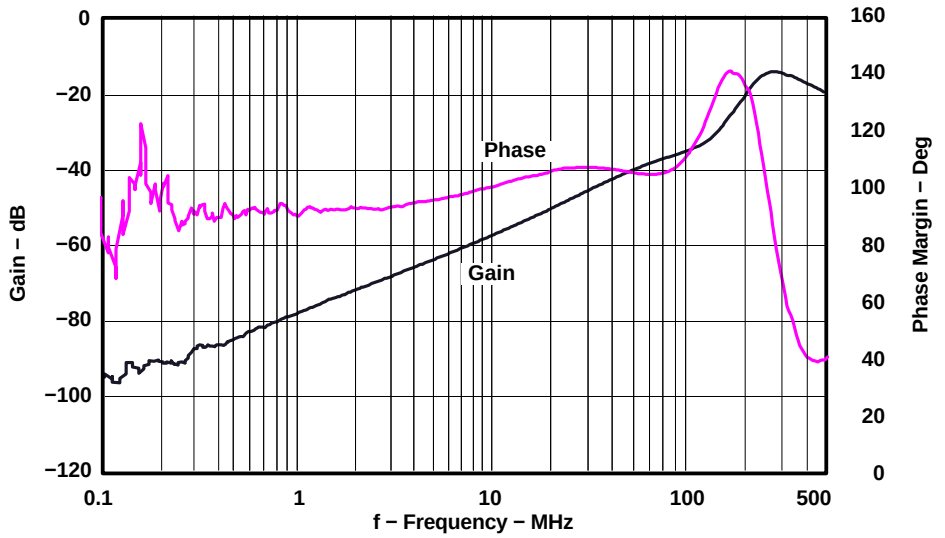
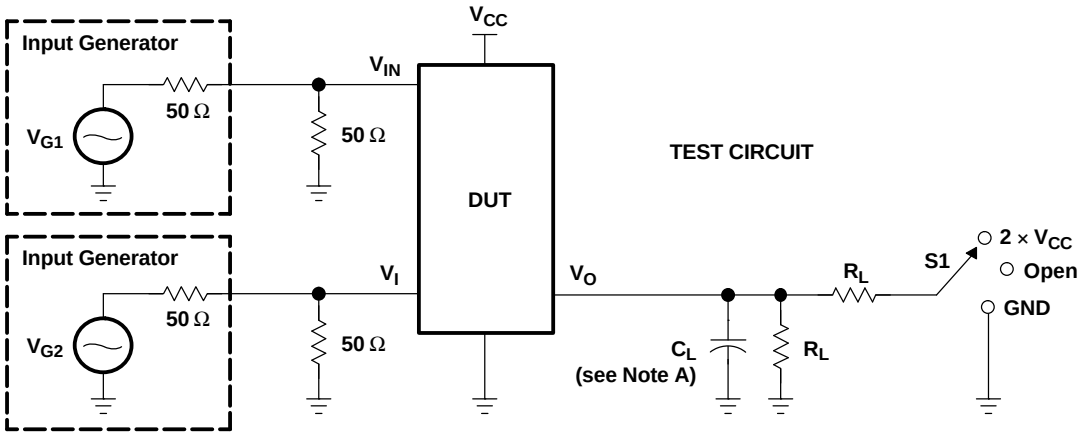


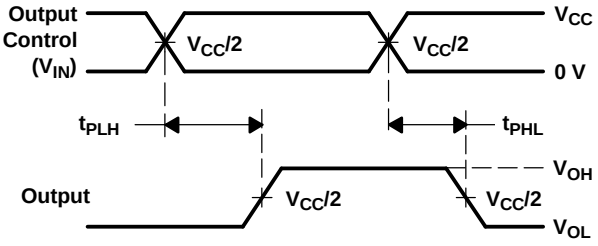
Figure 4. Frequency Response vs Crosstalk

PARAMETER MEASUREMENT INFORMATION

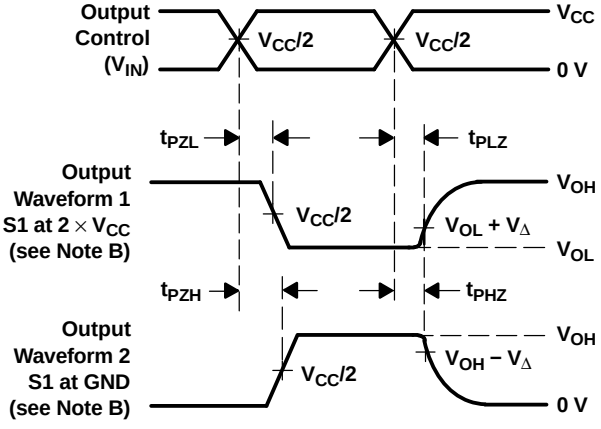


TEST	V_{CC}	S1	R_L	V_I	C_L	V_Δ
$t_{pd(s)}$†	5 V ± 0.25 V	Open	100 Ω	V_{CC}	35 pF	
t_{PLZ}/t_{PZL}	5 V ± 0.25 V	2 × V_{CC}	100 Ω	GND	35 pF	0.3 V
t_{PHZ}/t_{PZH}	5 V ± 0.25 V	GND	100 Ω	V_{CC}	35 pF	0.3 V

† t_{pds} is measured with Demux inputs at opposite voltage levels, i.e. V_{B1} = 5 V, V_{B2} = GND.



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES ($t_{pd(s)}$)



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES

NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r < 25 ns, t_f < 25 ns.
D. The outputs are measured one at a time, with one transition per measurement.
E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
F. t_{PZL} and t_{PZH} are the same as t_{en}.
G. t_{PLH} and t_{PHL} are the same as $t_{pd(s)}$. The tpd propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
H. All parameters and waveforms are not applicable to all devices.

Figure 5. Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION

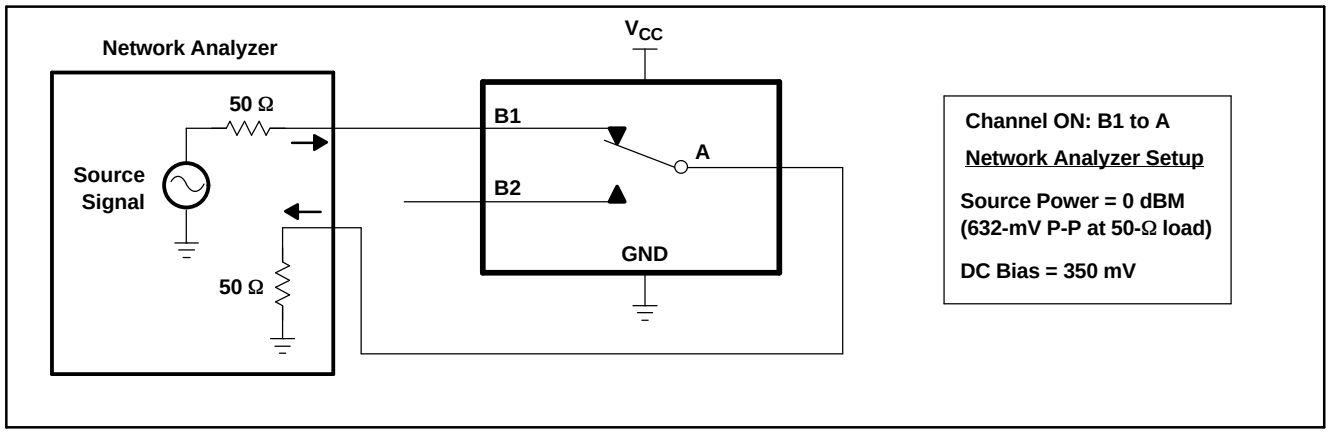


Figure 6. Bandwidth (BW)

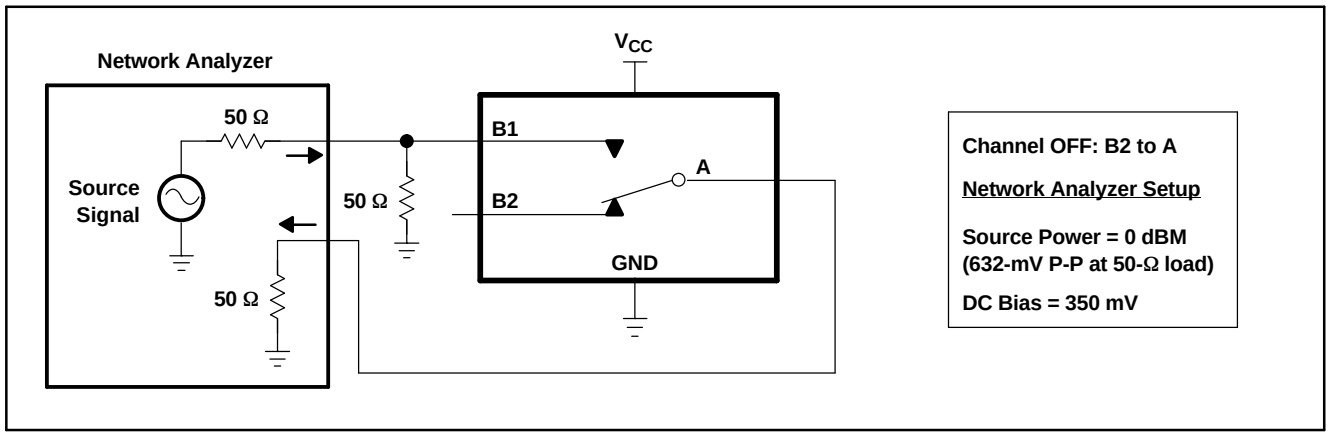


Figure 7. OFF Isolation (O_{ISO})

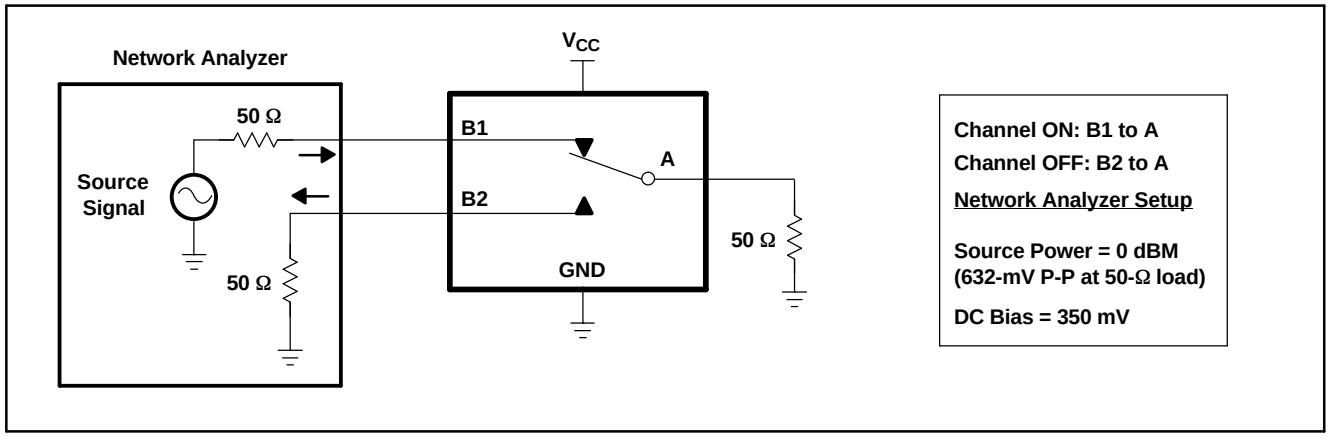


Figure 8. Crosstalk (X_{TALK})

PARAMETER MEASUREMENT INFORMATION (continued)

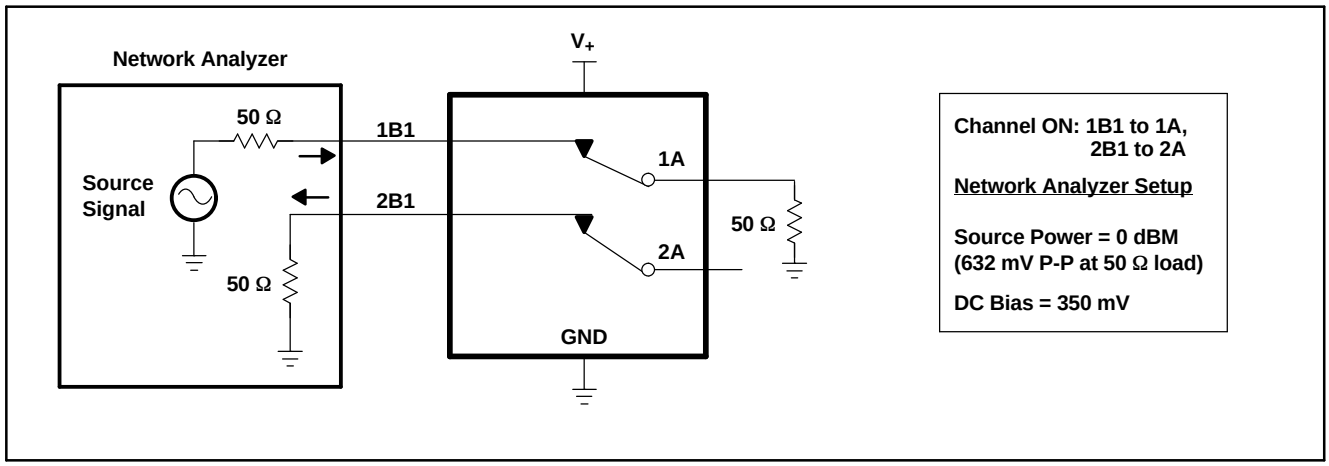
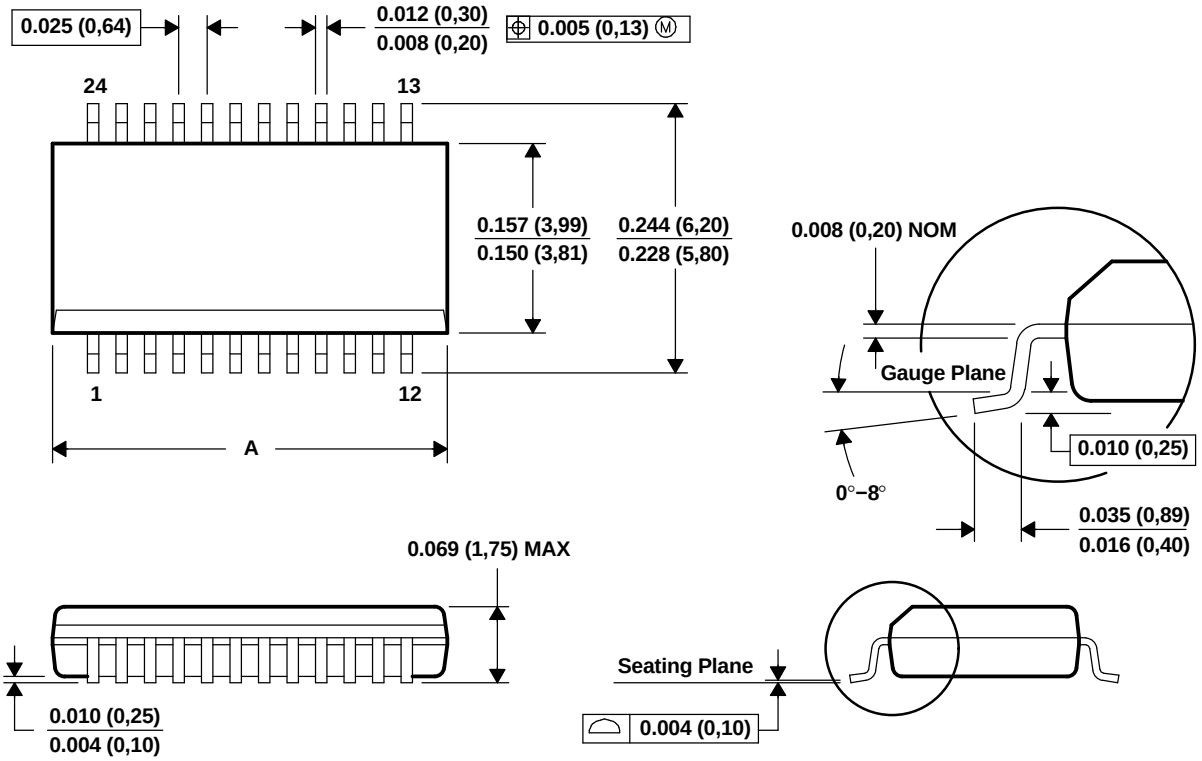


Figure 9. Adjacent Channel Crosstalk (X_{TALK})

MECHANICAL DATA

DBQ (R-PDSO-G**)



DIM \ PINS **	16	20	24	28
A MAX	0.197 (5,00)	0.344 (8,74)	0.344 (8,74)	0.394 (10,01)
A MIN	0.189 (4,80)	0.337 (8,56)	0.337 (8,56)	0.386 (9,80)
M0−137 VARIATION	AB	AD	AE	AF

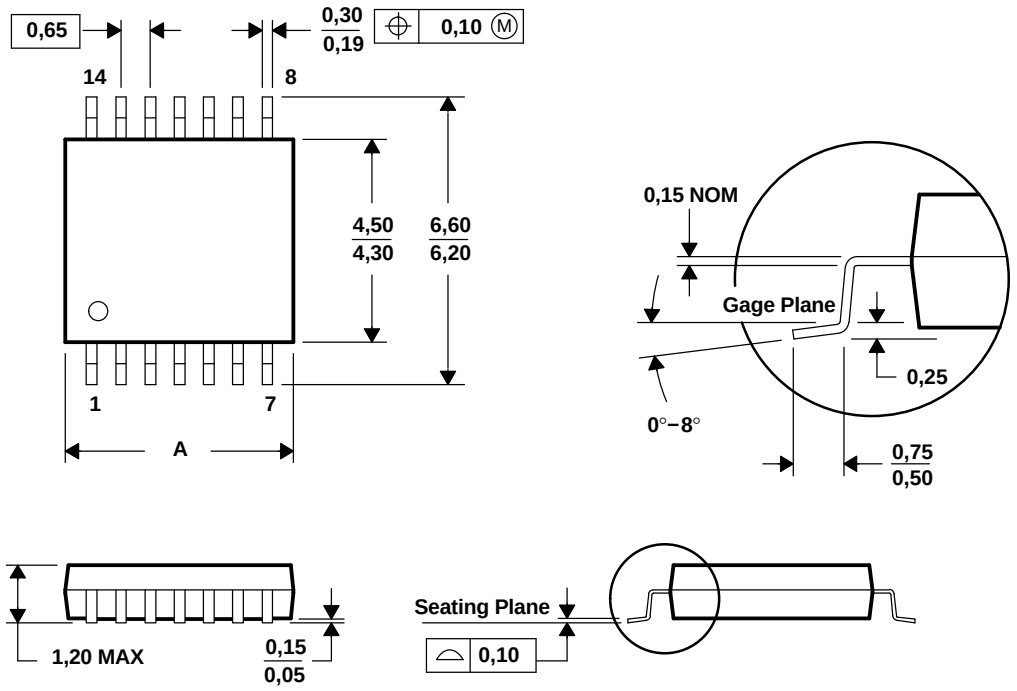
4073301/F 02/2002

NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
D. Falls within JEDEC MO−137.

MECHANICAL DATA

PW (R-PDSO-G**)

14 PINS SHOWN



DIM \ PINS **	8	14	16	20	24	28
A MAX	3,10	5,10	5,10	6,60	7,90	9,80
A MIN	2,90	4,90	4,90	6,40	7,70	9,60

4040064/F 01/97

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
D. Falls within JEDEC MO-153

PACKAGE OPTION ADDENDUM

27-Feb-2006

PACKAGING INFORMATION

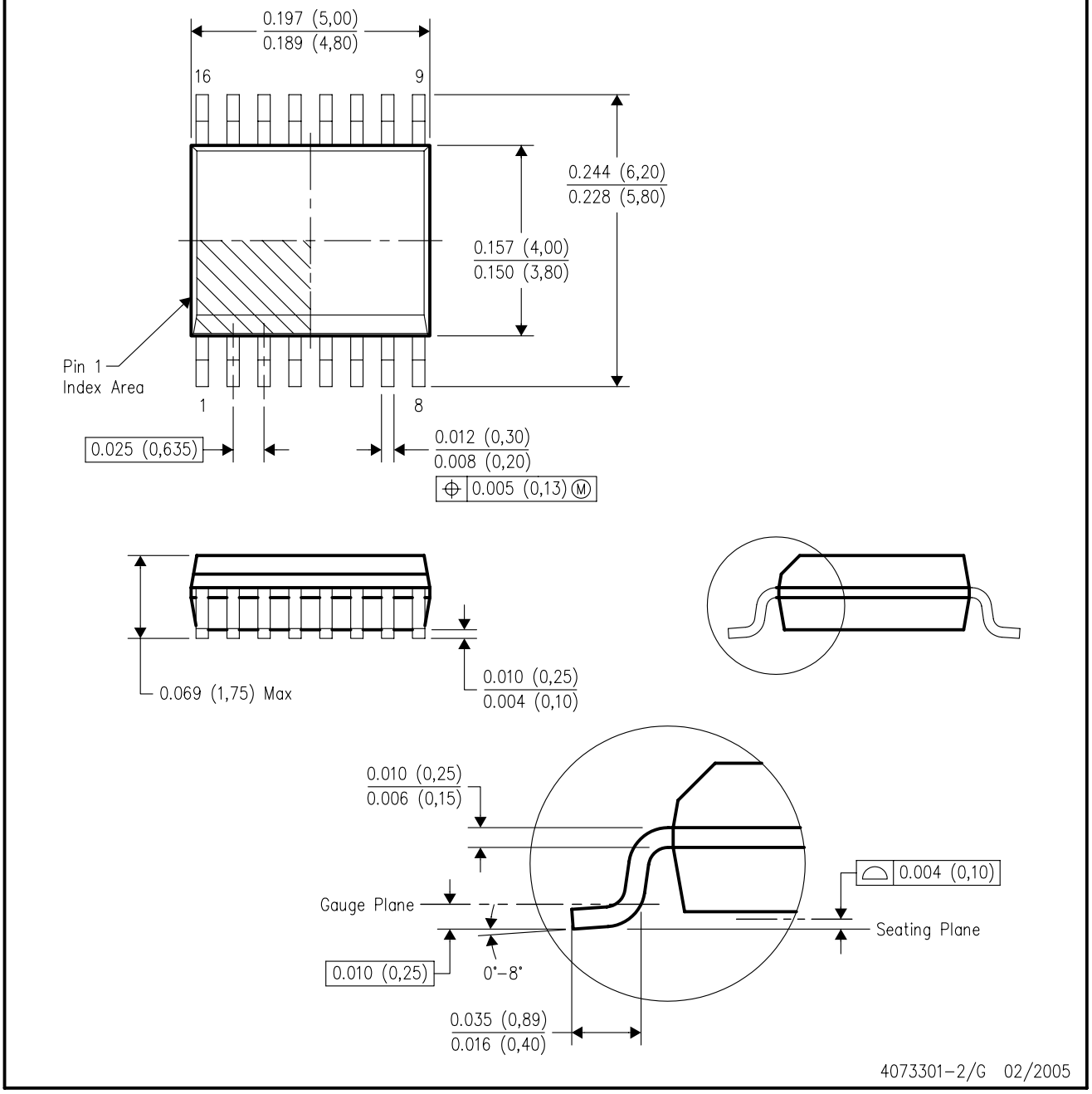
Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)
TS5N412DBQR	ACTIVE	SSOP/ QSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
TS5N412DBQRE4	ACTIVE	SSOP/ QSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
TS5N412PWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS5N412PWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

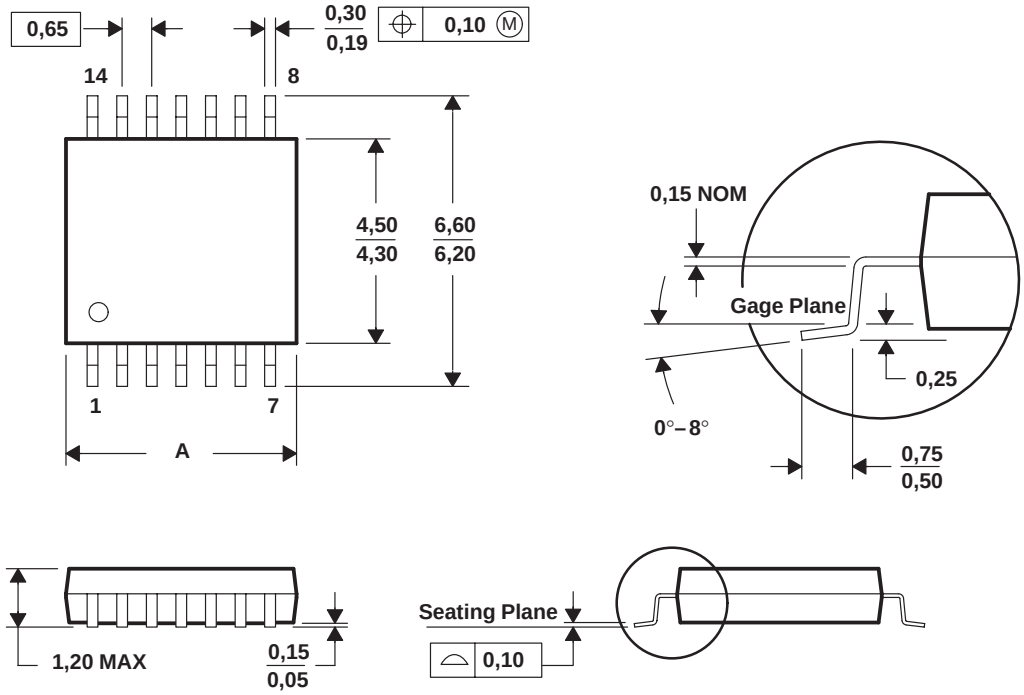
DBQ (R–PDSO–G16) PLASTIC SMALL–OUTLINE PACKAGE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
D. Falls within JEDEC MO–137 variation AB.

PW (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14 PINS SHOWN



DIM \ PINS **	8	14	16	20	24	28
A MAX	3,10	5,10	5,10	6,60	7,90	9,80
A MIN	2,90	4,90	4,90	6,40	7,70	9,60

4040064/F 01/97

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
D. Falls within JEDEC MO-153

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